Most Frequently Occurring Classifications of Patents Returned
From A Search of 09/942,338 on March 26, 2004

Combined Classifications
18 257/E27.103
15 365/185.18
13 257/E29.306
12 365/185.14
10 365/185.28
9 257/315
9 365/185.27
8 365/185.1
7 257/316
7 257/321
7 365/185.29
6 257/314
6 365/185.03
6 365/185.08
6 365/218
4 257/322
4 257/E21.682
4 257/E29.129
4 257/E29.304
4 365/185.01
4 365/185.2
4 365/185.26
4 365/225.6
4 438/257
4 438/258
3 257/317
3 257/320
3 257/E21.422
3 365/185.12
3 365/185.15
3 365/185.16
3 365/185.21
3 365/185.3
3 365/185.33
3 438/266
2 257/298
2 257/319
2 257/325
2 257/326
2 257/E21.68
2 257/E29.303
2 365/185.05
2 365/185.06
2 365/185.22
2 365/185.31
2 438/267

15 365/185.18   (3 OR, 12 XR)
    Class   365 : STATIC INFORMATION STORAGE AND RETRIEVAL
    365/185.01   FLOATING GATE
    365/185.18   .Particular biasing

12 365/185.14   (9 OR, 3 XR)
    Class   365 : STATIC INFORMATION STORAGE AND RETRIEVAL
    365/185.01   FLOATING GATE
    365/185.05   .Particular connection
    365/185.14   ..Program gate

10 365/185.28   (2 OR, 8 XR)
    Class   365 : STATIC INFORMATION STORAGE AND RETRIEVAL
    365/185.01   FLOATING GATE
    365/185.18   .Particular biasing
    365/185.28   ..Tunnel programming

9 257/315   (1 OR, 8 XR)
    Class   257 : ACTIVE SOLID-STATE DEVICES
    257/264   ...Enhancement mode or with high resistivity channel (e.g., doping of 10
15 cm -3 or less)
    257/288   .Having insulated electrode (e.g., MOSFET, MOS diode)
    257/314   ..Variable threshold (e.g., floating gate memory device)
    257/315   ...With floating gate electrode

9 365/185.27   (1 OR, 8 XR)
    Class   365 : STATIC INFORMATION STORAGE AND RETRIEVAL
    365/185.01   FLOATING GATE
    365/185.18   .Particular biasing
    365/185.27   ..Substrate bias

8 365/185.1   (1 OR, 7 XR)
    Class   365 : STATIC INFORMATION STORAGE AND RETRIEVAL
    365/185.01   FLOATING GATE
    365/185.05   .Particular connection
    365/185.1   ..Extended floating gate

7 257/316   (2 OR, 5 XR)
    Class   257 : ACTIVE SOLID-STATE DEVICES
    257/264   ...Enhancement mode or with high resistivity
        channel (e.g., doping of 10 15 cm -3 or less)
    257/288   .Having insulated electrode (e.g., MOSFET, MOS diode)
    257/314   ..Variable threshold (e.g., floating gate memory device)
    257/315   ...With floating gate electrode
    257/316   ....With additional contacted control electrode

7 257/321   (3 OR, 4 XR)
    Class   257 : ACTIVE SOLID-STATE DEVICES
    257/264   ...Enhancement mode or with high resistivity
        channel (e.g., doping of 10 15 cm -3 or less)
    257/288   .Having insulated electrode (e.g., MOSFET, MOS diode)
    257/314   ..Variable threshold (e.g., floating gate memory device)
    257/315   ...With floating gate electrode
    257/316   ....With additional contacted control electrode
    257/321   .....With thin insulator region for charging or
        discharging floating electrode by quantum mechanical tunneling

7 365/185.29 (2 OR, 5 XR)
    Class 365 : STATIC INFORMATION STORAGE AND RETRIEVAL
    365/185.01   FLOATING GATE
    365/185.18   .Particular biasing
    365/185.29   ..Erase

6 257/314   (3 OR, 3 XR)
    Class 257 : ACTIVE SOLID-STATE DEVICES
    257/264   ...Enhancement mode or with high resistivity   channel (e.g., doping of 10
15 cm -3 or less)
    257/288   .Having insulated electrode (e.g., MOSFET, MOS diode)
    257/314   ..Variable threshold (e.g., floating gate memory device)

6 365/185.03 (4 OR, 2 XR)
    Class 365 : STATIC INFORMATION STORAGE AND RETRIEVAL
    365/185.01   FLOATING GATE
    365/185.03   .Multiple values (e.g., analog)

6 365/185.08 (2 OR, 4 XR)
    Class 365 : STATIC INFORMATION STORAGE AND RETRIEVAL
    365/185.01   FLOATING GATE
    365/185.05   .Particular connection
    365/185.08   ..With volatile signal storage device

6 365/218   (1 OR, 5 XR)
    Class 365 : STATIC INFORMATION STORAGE AND RETRIEVAL
    365/189.01   READ/WRITE CIRCUIT
    365/218   .Erase

PLUS Search Results for S/N 09/942,338, Searched March 26, 2004 (Top 50)

The Patent Linguistics Utility System (PLUS) is a USPTO automated search
system for U.S. Patents from 1971 to the present. PLUS is a
query-by-example search system which produces a list of patents that are
most closely related linguistically to the application searched. This
search was prepared by the staff of the Scientific and Technical
Information Center, SIRA.

4597000	6088263	6479863	5898613	6212100
4486859	6091634	6534816	6125053	6212100
5208772	6127225	5933732	6144581	6246612
4458407	6159800	6236082	5659504	4274012
5867425	6277689	6424000	6144586	5329487
5872732	6177703	6580642	5990512	5781471
5896315	4435788	5295107	6243293	5912488
5926418	5606522	5428578	5801993	6009013
6026017	4429326	5526315	5859454	6016272
6027974	6384451	6058043	6034892	